

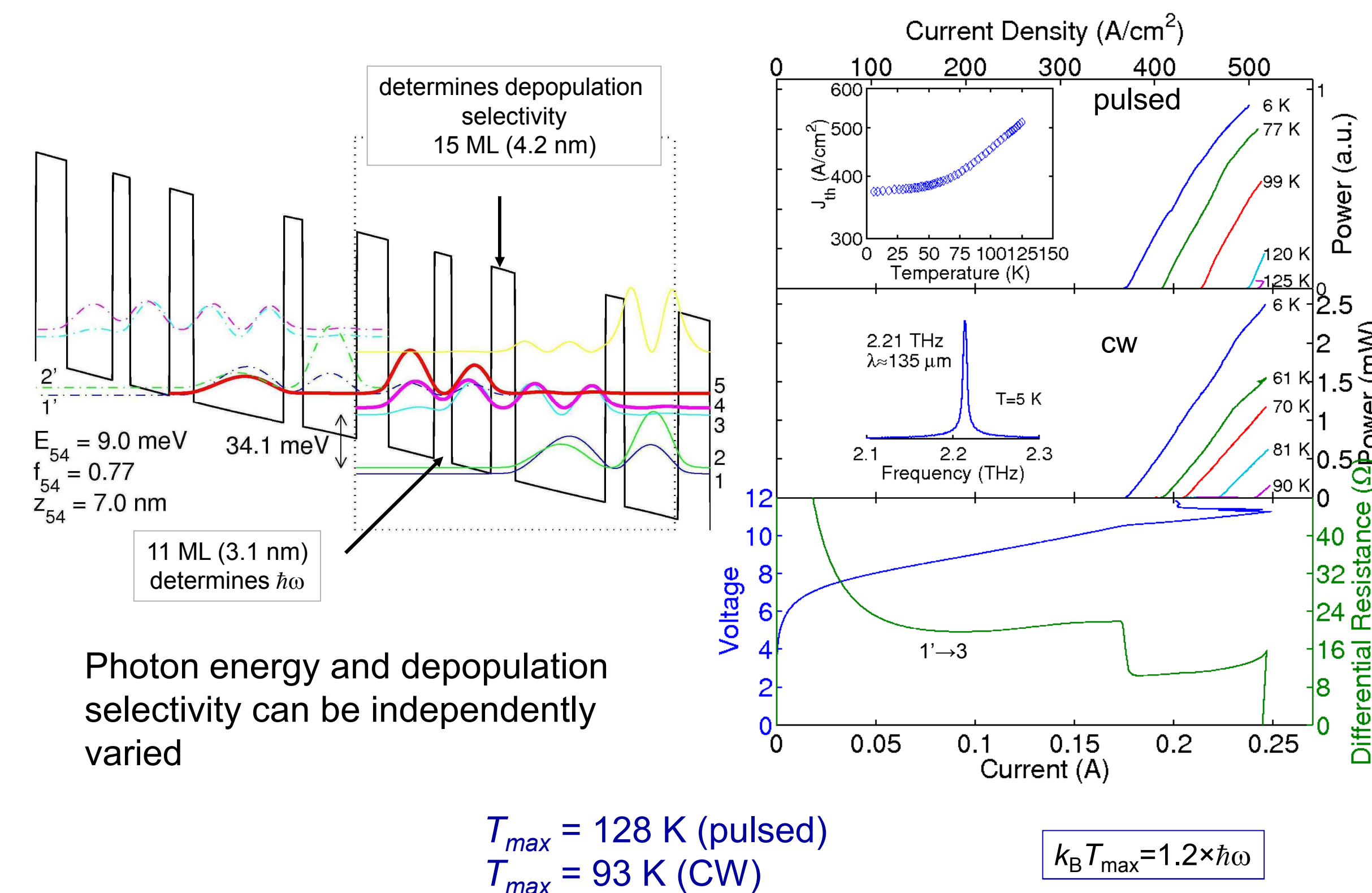
MBE AlGaAs Growth of:

- High Purity Materials
- High Mobility Materials
- High Precision Composition and Thickness Controlled Materials

Present Research Applications:

- Quantum Transport
- Quantum Wires
- Quantum Point Contacts
- Intersubband Transitions
- Bloch Oscillators
- Quantum Cascade Lasers (THz and IR)
- Plasmon THz Detectors
- QWIPs

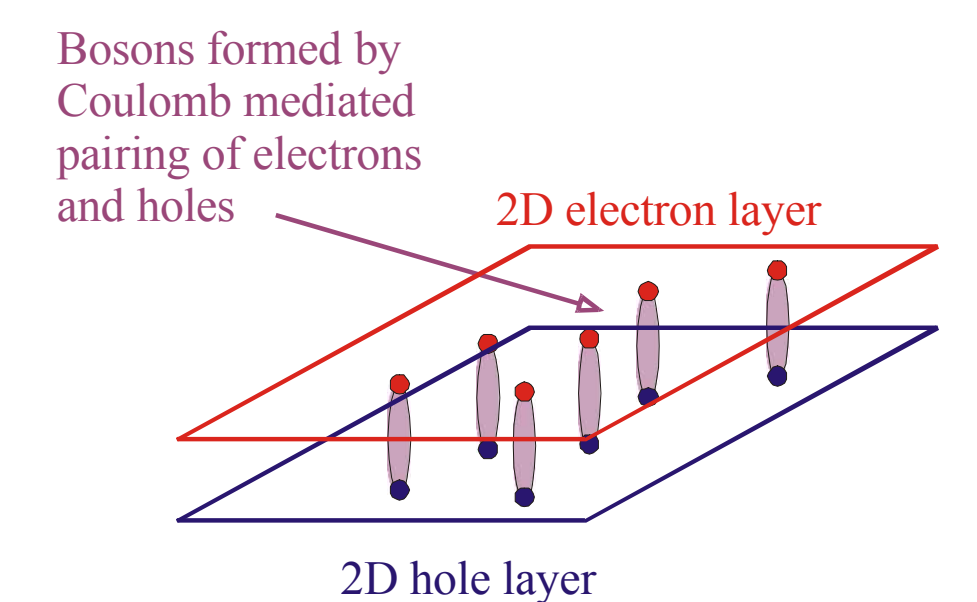
2.2 THz ($\lambda=135 \mu\text{m}$) Resonant-Phonon QCL



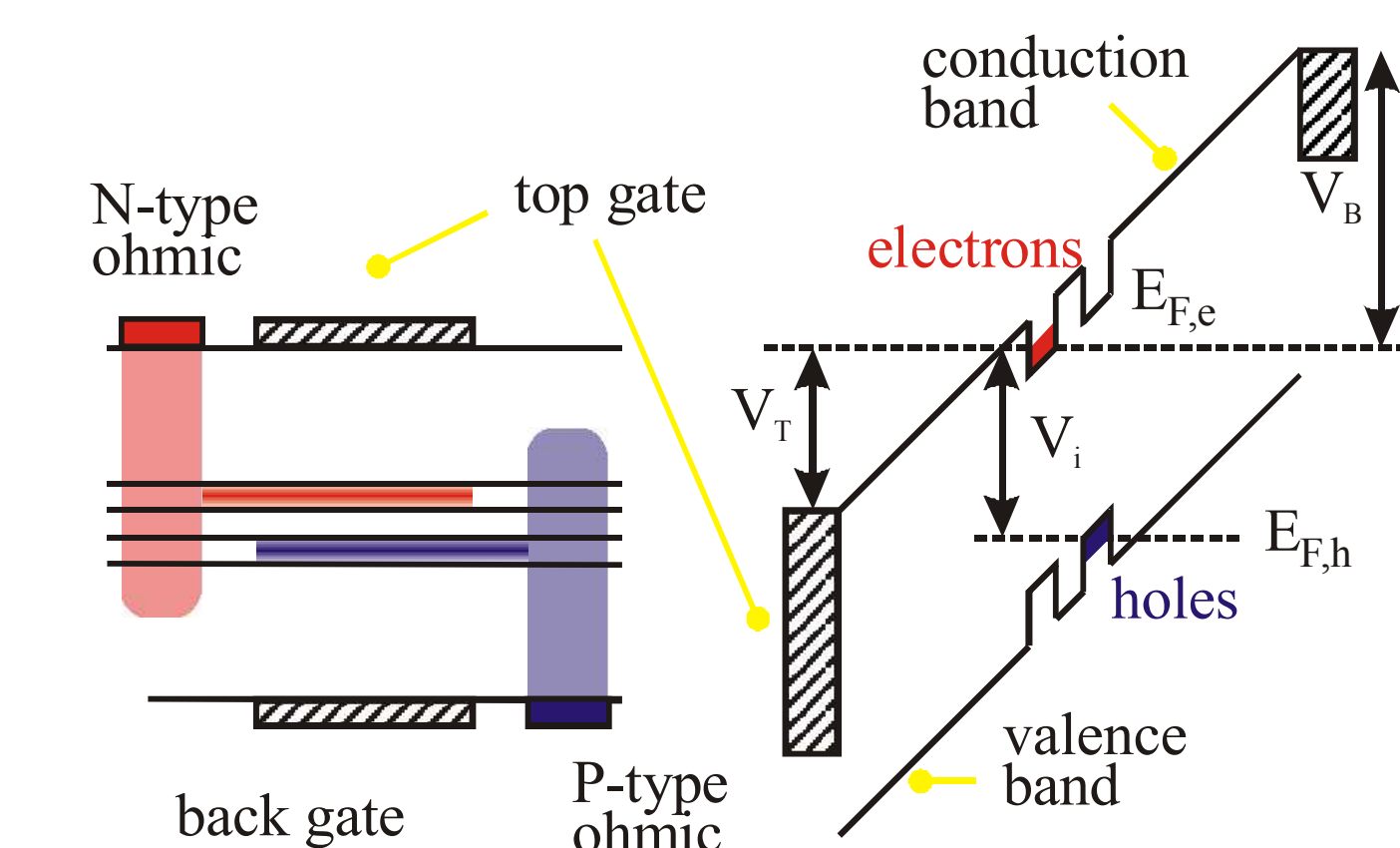
Search for exciton condensation in electron-hole bilayers

Search for superconducting transition requires:

1. closely spaced layers
2. low density
3. low temperature
4. high mobility



Implementation based on undoped GaAs heterostructures



1D-1D tunneling spectroscopy in coupled quantum wires

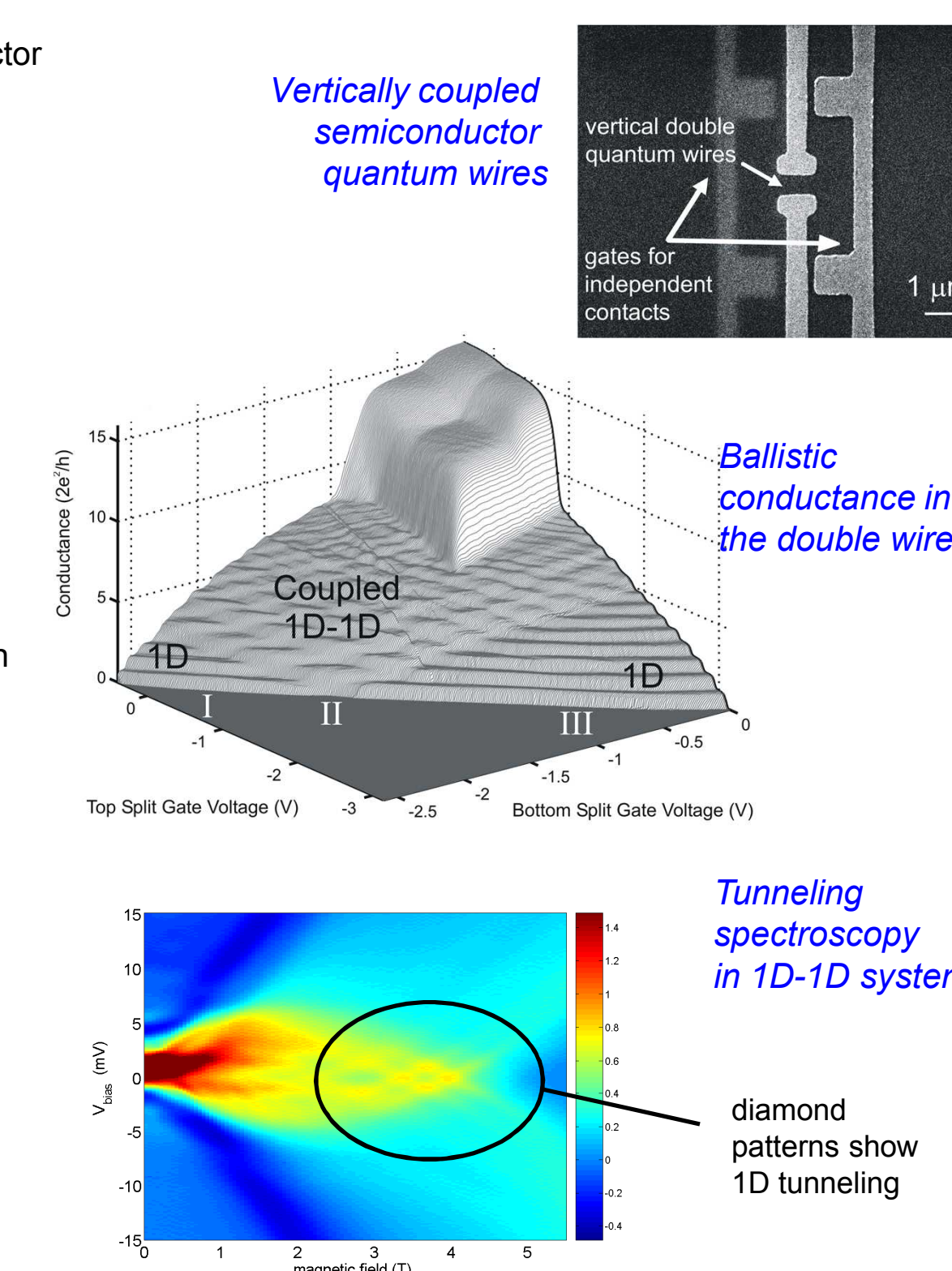
Why Sandia: Unique capabilities in state-of-the-art semiconductor material growth, and semiconductor nanostructure fabrication.

The Science Question: Can electrons be precisely controlled and manipulated at the wavefunction level?

Accomplishment: We have measured quantum electron tunneling between two 1D wires, whose quantized energy levels can be independently controlled.

What is the progress/answer: The tunneling data shows a complex pattern that reflects energy subband occupations in a systematic way. This clearly demonstrates precise control of electron nanostructures at the wavefunction level.

Why it matters: This work demonstrates a new technique for approaching nanoscale physics questions, such as if 1D electron systems are Fermi liquids or novel collective states of matter. It could also impact quantum computing.



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